## 10/568186 IAP20 Rec'd PCT/FTO 13 FEB 2006

## **PATENT APPLICATION**

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## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Izumi FUSEGAWA et al.

Application No.: New U.S. National Stage of PCT/JP2004/011685

Filed: February 13, 2006 Docket No.: 126961

For: METHOD FOR PRODUCING A SINGLE CRYSTAL AND SILICON SINGLE

CRYSTAL WAFER

## **PRELIMINARY AMENDMENT**

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Please consider the following:

Amendments to the Specification;

Amendments to the Claims as reflected in the listing of claims; and

Remarks.